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**FACSIMILE COVER SHEET**

To: Examiner Tu-Tu Ho	Total Pages Sent: 14
Technology Center 2800	(including cover sheet)
Facsimile Number: 571-273-8300	Transmission Date: December 2, 2005

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

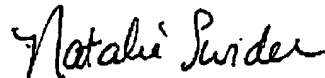
Applicant: Bao, et al. Docket No.: TSM03-0927  
Serial No: 10/800,510 Art Unit: 2818  
Date Filed: March 15, 2004  
Title: Semiconductor Device Having a Second Level of Metallization Formed over a First Level with Minimal Damage to the First Level and Method

**CERTIFICATION OF FACSIMILE TRANSMISSION**

I hereby certify that the following papers are being transmitted by facsimile to the U.S. Patent and Trademark Office at 571-273-8300 on the date shown above:

- Certification of Facsimile Transmission (1 page)
- Petition for Extension of Time - 1 month (1 original and 1 copy = 2 pages)
- Amendment (9 pages)
- Affidavit Filed Under 37 C.F.R. § 1.132 (2 pages)

Respectfully submitted,



Natalie Swider  
Legal Assistant

**Confirmation Respectfully Requested**

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